D ynam ical and point sym metry of the K ondo e ect in triangular quantum dot

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In this work we concentrate on the point sym m etry of triangular triple quantum dot and its interplay with the spin rotation sym m etry in the context of K ondo tunneling through this kind of artical molecule. A fully sym metric triangular triple quantum dot is considered, consisting of three identical puddles with the same individual properties (energy levels and C oulomb blockade parameters) and inter-dot coupling (tunnel amplitudes and electrostatic interaction). The underlying K ondo physics is determined by the product of a discrete rotation sym metry group in real space and a continuous rotation sym metry in spin space. These sym metries are rejected in the resulting exchange ham iltonian which naturally involves spin and orbital degrees of freedom. The ensuing poor-m an scaling equations are solved and the K ondo temperature is calculated.

## I. INTRODUCTION

The analogy between complex quantum dots and real molecules was recognized both by experimentalists and theoreticians at early stage of studies of these articial nanoobjects (see, e.g.,  $^{1,2}$ ). Soon after the discovery of the K ondo e ect in tunneling through quantum dots (QD)<sup>3</sup>, it was recognized that this phenomenon may be realized in tunneling through complex quantum dots consisting of two or three electron puddles (double ant triple quantum dots)<sup>4,5,6,7</sup>. Tunneling through these "articial linear molecules" has been studied mainly in serial and parallel con gurations, where the dots are ordered linearly either parallel or perpendicular to the metallic leads. Meanwhile, modern experimental methods allow also fabrication of quantum dots in a triangular geometry. Triangular triple quantum dot (TTQD) was considered theoretically and realized experimentally very recently, in order to demonstrate the ratchet e ect in single electron tunneling. To achieve this e ect the authors proposed a conguration, where two of the three puddles are coupled in series with the leads (source and drain), while the third one has a tunnel contact with one of its counterparts and only a capacitive coupling with the other.

In this paper we concentrate on the point symmetry of TTQD and its interplay with the spin rotation symmetry in a context of K ondo tunneling through this artical molecule. Indeed, the generic feature of K ondo e ect is the involvement of internal degrees of freedom of localized "scatterer" in the interaction with continuum of electron-hole pair excitations in the Fermisea of conduction electrons. These are spin degrees of freedom in conventional K ondo e ect, although in some cases the role of pseudospin may be played by conguration quantum numbers, like in two-level systems and related objects. TTQD may be considered as a specic K ondo object, where both spin and conguration excitations are involved in cotunneling on equal footing.

To dem onstrate this interplay, we consider a fully sym metric TTQD consisting of three identical puddles with the same individual properties (energy levels and C oulom b blockade parameters) and inter-dot coupling (tunnelam plitudes and electrostatic interaction. Like in the above mentioned triangular ratchet<sup>8,9</sup>, we assume that the TTQD in the ground state is occupied by one electron and C oulom b blockade is strong enough to completely suppress double occupancy of any valley j = 1;2;3. This means that the only mechanism of electron transfer through TTQD is cotunneling, where one electron leaves the valley j for metallic leads, whereas another electron tunnels from reservoir to the same valley j or to another valley 1. In the former case only the spin reversal is possible, whereas in the latter case not only the spin is a ected but also the TTQD is electively "rotated" either clockwise or anti-clockwise (see Fig. 1).

D iscrete rotation in real space and continuous rotation in spin space may be described in terms of group theory. The group  $C_{3v}$  characterizes the symmetry of triangle, and the group SU (2) describes the symmetry of spin 1/2. So the total symmetry of TTQD is determined by direct product of these two groups. One may use an equivalent language of permutation group  $P_3$  for description of conguration of TTQD with an electron occupying one of three possible positions in its wells.

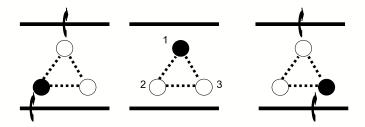


FIG. 1: Triangular triple quantum dot (TTQD) in a contact with source (s) and drain (d) leads. C lockwise (c) and anti-clockwise (a) "rotation" of TTQD due to cotunneling through the channels  $V_{\rm s3}$  and  $V_{\rm s2}$ , respectively.

## II. HAM ILTONIAN OF ARTIFICIAL TRIANGULAR MOLECULE

A symmetric TTQD in a contact with source and drain leads (Fig. 1) is described by the Hamiltonian

$$H = H_d + H_{lead} + H_t:$$
 (1)

The  $\,$  rst term  $\,$  H  $_{\rm d}$  is the H am iltonian of the isolated TQD ,

where = ";# is the spin index, hjli = h12i;h23i;h31i. Q and Q  $^{0}$  are intra-dot and inter-dot Coulomb blockade parameters, W  $_{\rm jl}$  are inter-dot tunneling parameters. The second term H  $_{\rm lead}$  describes the electrons in the source (s) and drain (d) electrodes,

$$H_{lead} = X X X k_b c_{kb}^y c_{kb} :$$

$$k_b = s_{rd}$$
(3)

The last term  $H_t$  is the tunneling H am iltonian

$$H_{t} = \begin{pmatrix} X & X \\ X & X \\ 0 & V_{sj}C_{ksj}^{y} d_{j} + V_{s}d_{kd}^{y} d_{1} + H & x.^{A} :$$
(4)

which describes a con guration with two-channel tunneling between the TTQD and the source and single-channel tunneling between the TTQD and the drain. If all three channels are equivalent,

$$V_{d} = V_{s2} = V_{s3} V;$$
 (5)

the tunnel contacts preserve the rotation/perm utation sym metry of TTQD. If all tunnel constants are dierent, this sym metry is completely destroyed by tunneling. In the intermediate case

$$V_d \in V_{s2} = V_{s3} \qquad V_s; \tag{6}$$

the system preserves one m irror rejection axis (2 \$ 3). The K ondo tunneling regime w ill be analyzed both in cases (5) and (6).

The Ham iltonian H (1) is easily diagonalized by using the following set of basis functions  $jj i = d_j^y$  j0i (j = 1;2;3). The eigenfunctions of sym m etric TTQD in this basis are

$$_{;\mathbb{A}_{1}} = \frac{1}{\frac{1}{3}} (j\mathbb{1} \ i + j\mathbb{2} \ i + j\mathbb{3} \ i);$$

$$_{;\mathbb{E}_{(+)}} = \frac{1}{\frac{1}{3}} (j\mathbb{1} \ i + e^{2i'} j\mathbb{2} \ i + e^{i'} j\mathbb{3} \ i);$$

$$_{;\mathbb{E}_{(-)}} = \frac{1}{\frac{1}{3}} (j\mathbb{1} \ i + e^{i'} j\mathbb{1} \ i + e^{2i'} j\mathbb{3} \ i)$$

with ' = 2 = 3. Here A  $_1$  and E are two irreducible representations of the group C  $_{3v}$  The spin states with N = 1 are spin doublets (D), so the Ham iltonian of isolated TTQD in this charge sector has six eigenstates D A i; D E i . The single electron energies are

$$E_{DA_1} = + 2W;$$
  $E_{DE} = W:$  (8)

First of these energy levels is a conventional spin doublet with fully symmetrical "orbital" wave function  $A_1$ . The second one is doubly degenerate both in spin and orbital quantum number.

A peculiar feature of the three-site con guration is an explicit dependence of the order of levels in spin multiplet on the sign of tunnel integral W. The ground state is a spin doublet  $E_{D,R_1}$ , provided W<0. In case of W>0 the lowest level is the orbital doublet  $E_{D,E}$ . The orbital degeneracy of the states E ( ) is a manifestation of rotation/permutation degrees of freedom of TTQD illustrated by F ig. 1. These discrete rotations are explicitly involved in K ondo tunneling.

## III. KONDO TUNNELING THROUGH PARTIALLY OCCUPIED TTQD

A contact between sym m etric TTQD and leads in the two-term inalgeom etry preserves rotation sym m etry C $_{3v}$  (P $_3$ ) unless the tunnel H am iltonian H  $_t$  has lower sym m etry than TTQD. In any case it is useful to re-expand the tunnel H am iltonian in partial waves, which respect the "point sym m etry" of the H am iltonian H . Such ansatz is known in the theory of K ondo e ect in 3D m etal, where the spherical partial wave representation for B loch electrons in conduction band was introduced in Ref. [11]. Later on, this approach was extended by m any authors to the case of point crystal group representation (see, e.g., the review [10]). Here we also meet the situation where the triangular quantum dot imposes its point sym metry on the continuum of electron states in the leads under certain conditions.

If the condition (5) is satis ed, the point sym m etry of the device as a whole is still  $C_{3v}$ , and the band states m ay be re-expanded as

$$c_{A,jk;} = \frac{1}{3} (c_{d,k}; + c_{s_{2},k}; + c_{s_{3},k};);$$

$$c_{E,(+),jk;} = \frac{1}{9} c_{d,k}; + e^{2i'} c_{s_{2},k}; + e^{i'} c_{s_{3},k}; ;$$

$$c_{E,(-),jk;} = \frac{1}{9} c_{d,k}; + e^{i'} c_{s_{2},k}; + e^{2i'} c_{s_{3},k}; ;$$

$$(9)$$

which has the same angular dependence as (7).

The Anderson Ham iltonian H rewritten in these variables may be expressed by means of Hubbard operators  $X = j ih^{-0}j$  with = 0; ; :

$$H = E_{0}X^{00} + E_{0}X + E$$

Here  $\mathcal{D}$ i stands for an empty TTQD, ji=  $\mathcal{D}$ A<sub>1</sub>i;  $\mathcal{D}$ E i belong to the single electron charge sector, and ji are the eigenvectors of two-electron states. The eigenstates E for N = 2 are

$$E_{SA_{1}} = {}_{2} + 2W = \frac{8W^{2}}{Q};$$
 $E_{TE} = {}_{2} + W;$ 
 $E_{SE} = {}_{2} = W = \frac{2W^{2}}{Q};$ 
 $E_{TA_{2}} = {}_{2} = 2W:$  (11)

Here  $_2$  = 2 + Q $^0$ , indices S;T denote spin singlet and spin triplet con gurations of two electrons in TTQD, and the inequality W Q is used explicitly. The irreducible representation A $_2$  contains two-electron eigenfunction, which is odd with respect to permutations j\$ l. Like in the singly occupied TTQD, the level ordering is sensitive to the sign of tunnel integral W .

The tunnelmatrix elements are rede ned accordingly.

$$V^0 = h_c$$
;  $\mathcal{H}_t$ j i;  $V = h_c$ ;  $\mathcal{H}_t$ j i:

The matrix elements intermixing the charge sectors N=1;2, add conduction electron  $^0$  to the dot electron , and the resulting two-electron states arise in accordance with C lebsch-G ordan coe cients both in spin and orbital subspaces  $C^{\infty}_{0}C^{M}_{0}$  where =A;E ( ), M=S;T.

We describe K ondo tunneling by means of Haldane-Anderson renormalization group (RG) approach  $^{12,13}$ . A coording to this procedure the parameters of the original Hamiltonian are renormalized in the course of rescaling of the energy D characterizing the width of conduction electron continuum in the leads from original value D0 to the energy  $T_{\rm K}$ , which characterizes K ondo correlations. The latter is found from the solution of scaling equations. First, the energy levels E are renormalized by the virtual excitations of the states  $\rm Di$  and  $\rm j$  i. The ow equations have the form

$$E_A (D) = + 2W \qquad \ln (D_0 = D);$$
  
 $E_E (D) = W \qquad \ln (D_0 = D);$  (12)

where  $_{0}V^{2}$  is the tunneling rate,  $_{0}$  is the density of electron states in the leads. This scaling ends at D ! D, with D de ned as

(Schrie er-W ol lim it)  $^{12}$ . Besides, the Haldane-Anderson procedure generates elective two-particle vertices J, which describe elective exchange interaction between dot and lead electrons. Various cotunneling processes contribute to this interaction. In conventional K ondo problem the elective low-energy exchange Hamiltonian has the form JS s, where S and s are the spin operators for dot and lead electrons, respectively  $^{13}$ . Here we are in a position, where the low-energy states of the quantum dot are represented by a multiplet containing both spin and orbital indices. In this case the form of elective Hamiltonian is predetermined by a dynamical symmetry of the Hamiltonian H  $_{\rm d}^{5,14}$ .

The dynam ical sym m etry group of a given H am iltonian is determ ined not only by the operators, which leave this H am iltonian invariant but also by the operators describing transitions between dierent energy levels of the multiplet. It follows from this de nition that the dynam ical sym m etry m ay vary depending on the set of energy levels which fall into an actual energy interval. In particular, it changes in the process of rescaling the energy interval in the Anderson's RG procedure  $^{13}$ . If the condition D  $^{3}$ W is satisfied, then the dynam ical sym m etry is determined by the whole multiplet E. The dynam ical sym m etry group, which describes all possible transitions within the set fD  $A_1$ ; DE () is SU (6). Among 35 generators of this group are nine spin vectors S  $^{\circ}$  with projections defined as

$$S^{+}_{0} = X^{"}_{i}^{*}^{*}_{0}^{0}; S_{0} = X^{*}_{i}^{*}^{*}_{0}^{0};$$

$$S^{z}_{0} = \frac{1}{2} (X^{"}_{i}^{*}^{*}_{0}^{0} X^{*}_{i}^{*}^{*}_{0}^{0});$$
(13)

The rest 8 operators describe the permutation degrees of freedom of TTQD. In the process of further reduction of the energy scale D the highest of two levels E is quenched, and eventual sym m etry of K ondo e ect depends on the sign of tunneling am plitude  $\mathbb W$ .

In case of W < 0 the permutation degrees of freedom are quenched at low-energy scale. The only vector, which is involved in the K ondo cotunneling through TTQD is the spin  $S_{AA}$  de ned in Eq. (13). The lead states are still classi ed in accordance with the point sym metry of the system. As a result the SW Ham iltonian has the form

$$H_{SW} = J_E (S_{+}S + S_{-}S) + J_A S_{A}S; \qquad (14)$$

(the subindex A of spin operator of TQD is om itted). The exchange vertices J are

$$J_{E} = \frac{2V^{2}}{3} \frac{1}{+Q^{0}} \frac{1}{F} \frac{1}{+Q} ;$$

$$J_{A} = \frac{2V^{2}}{3} \frac{3}{F} + \frac{1}{+Q} \frac{2}{F} + \frac{2}{+Q^{0}} ;$$
(15)

The constant  $J_A$  has antiferrom agnetic sign like in conventional SW case, whereas the constant  $J_E$  is negative due to the inequality Q  $Q^0$ .

Form ally, the H am iltonian (14) describes three-channel cotunneling. However, two of three available exchange channels in the H am iltonian (14) are irrelevant for K ondo cotunneling, because the coupling constant  $J_E$  is negative (ferrom agnetic). As a result the conventional K ondo regime arises in D A channel with K ondo temperature

$$T_{K}^{(A)} = D \exp \frac{1}{0J_{A}}$$
: (16)

where  $_0$  is the density of electron states in the leads, which is assumed to be the same for all channels. In case of W > 0 the doublet  $E_{D\,A}$  is quenched at D < W , and the K ondo e ect is defined by the tunneling through TTQD in the state  $\mathcal D$ ; E i whose symmetry is SU (4). Similar situation was observed for a double quantum dot in series geometry. In that case the pseudospin variable describes two possible occupations of an electron in a double dot. The 15 generators of this group bunch in four spin vectors S  $_0$  with  $_0$  = E ( )) and one pseudospin vector T defined as

$$T^{+} = {\overset{X}{X}}^{+}; T = {\overset{X}{X}}^{+};$$

$$T^{z} = \frac{1}{2} {\overset{X}{X}}^{+}; {\overset{+}{X}}^{+} {\overset{+}{X}}^{-}; \qquad (17)$$

Here the indices stand for "orbital" indices E ( ) for the sake of brevity.

Due to high degeneracy of the ground state of TTQD, the e ective SW Ham iltonian acquires quite complicated form,

$$H_{SW} = J_{1} (S_{+} + s + S_{-} s) + J_{2} (S_{+} + s + S_{-} + s) + J_{3} (S_{+} + S_{-}) + J_{4} (S_{+} + S_{+} + S_{-} + s_{-}) + J_{5} (S_{+} + s_{+A}) + S_{-} + s_{+A}) + S_{-} + s_{-} (18)$$

w here

$$z = \frac{1}{2}^{X}$$
  $c_{+}^{y} c_{+}$  & c;

and the coupling constants  $J_{1\ 6}$  are

$$J_{1} = J_{4} = \frac{2V^{2}}{3} \frac{3}{F}$$

$$+ \frac{1}{+Q} + \frac{2}{+Q^{0}} + \frac{2}{+Q^{0}} :$$

$$J_{2} = J_{3} = J_{5}$$

$$= \frac{2V^{2}}{3} \frac{1}{+Q^{0}} + \frac{1}{+Q^{0}} :$$

$$J_{6} = \frac{V^{2}}{F} + \frac{V^{2}}{+Q^{0}} :$$

$$(19)$$

Both spin and "orbital" degrees of freedom of TTQD are involved in e ective Kondo tunneling. The indirect exchange coupling constants arise as combinations of cotunneling processes with virtual excitation of states with zero

and two electrons. It is worth m entioning that the rotation  $C_{3v}$  sym m etry in a system dot+ leads m ay be violated in the process of cotunneling unlike the rotation spin sym m etry [see the terms  $J_{3;5}$  in the H am iltonian (18)].

Some of these constants are positive  $(J_{1;4;6})$  like in conventional SW transform ation, and some are negative  $(J_{2;3;5})$ . Thus the K ondo elect arises as a result of interplay of antiferrom agnetic and ferrom agnetic exchange involving both spin and pseudospin variables. This interplay is described by scaling equations obtained in a fram ework of Anderson's "poorm an scaling" procedure<sup>13</sup>. The system of scaling equations describes the low of exchange vertices, with reducing the energy scale D from the boundary value D  $_{\text{SW}}$  to the K ondo temperature  $T_{\text{K}}$ . It has the following form:

$$\frac{dj_{1}}{dt} = j_{1}^{2} + \frac{j_{4}^{2}}{2} + j_{4} j_{6} + \frac{j_{5}^{2}}{2};$$

$$\frac{dj_{2}}{dt} = j_{2}^{2} + \frac{j_{4}^{2}}{2} j_{5} + \frac{j_{5}^{2}}{2};$$

$$\frac{dj_{3}}{dt} = j_{3}^{2} + j_{5}^{2};$$

$$\frac{dj_{4}}{dt} = [j_{4}(j_{1} + j_{2} + j_{6}) + j_{6}(j_{1} j_{2})];$$

$$\frac{dj_{5}}{dt} = \frac{j_{5}}{2}[j_{1} + j_{2} + j_{3} j_{3}];$$

$$\frac{dj_{6}}{dt} = \frac{j_{6}}{4}:$$
(20)

Here  $j_i = {}_0J_i$ , and the scaling variable is t = ln D.

A nalysis of solutions of the scaling equations (20) with initial values of coupling parameters listed in Eq. (19), shows that the symmetry-breaking vertices  $j_{3,5}$  are irrelevant, and the vertex  $j_2$ , which is negative at the boundary  $D = D_{SW}$  evolves into positive domain and eventually enters the K ondo temperature. The latter is given by the following equation

$$T_k = D \exp \frac{2}{j_1 + j_2 + 2j_4 + 2j_6}$$
: (21)

We see from this equation that both spin and pseudospin coupling contribute to the K ondo cotunneling on equal footing, so that  $T_K$  is enhanced due to involvement of additional degrees of freedom connected with electron permutations in a triangle.

The tunnel contact reduces the sym m etry of TTQD when the conditions (6) are satis ed. In this case the double orbital degeneracy of the level  $E_{D\,E}$  is rem oved by tunnel coupling. Then the generic sym m etry of TTQD is usual SU (2) sym m etry, but an accidental degeneracy between the levels  $E_{D\,E\,(+)}$  and  $E_{D\,A_1}$  arises under certain condition, and in this case the SU (4) sym m etry is restored. This situation as well as the properties of TTQD with N = 2 will be considered in m ore detailed forthcoming publication.

## IV. CONCLUSIONS

Dynam ical sym metry is a universal tool, which allows to derive the elective spin Hamiltonians describing low-energy cotunneling with spin reversal through composite quantum dots. These dots possess both the continuous rotation sym metry in spin space and discrete rotation sym metry in real space. We considered in this paper the relatively simple example of symmetric triangular quantum dot in contact with metallic leads in a special geometry where the dot imposes its discrete rotation symmetry on the electrons in the leads. The tunnel problem is mapped on the Coqblin-Schrie er (CS) modelofmagnetic impurity with "orbital" degrees of freedom. Like in the latter case, the symmetry of the Kondo center is SU (2n). The parameter notations additional orbital degeneracy in conventional CS model. In case of articial triangular molecule it describes the pseudospin operator of nite clockwise/anti-clockwise rotations of TTQD in the process of electron cotunneling.

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